

## 2.2 W Constant Output Power Class-D Audio Amplifier with Class-G Boost Converter

Check for Samples: [TPA2080D1](#)

### FEATURES

- 2.2 W into 4  $\Omega$  Load from 3.6 V Supply (1% THD+N)
- Integrated Class-G Boost Converter
  - Increases Efficiency at Low Output Power
- Low Quiescent Current of 3.5 mA from 3.6 V
- Thermal and Short-Circuit Protection with Auto Recovery
- 20 dB Fixed Gain
- Available in 1.53 mm  $\times$  1.98 mm, 0.5 mm pitch 12-ball WCSP (DSBGA) Package

### APPLICATIONS

- Cell Phones
- PDA, GPS
- Portable Electronics and Speakers

### DESCRIPTION

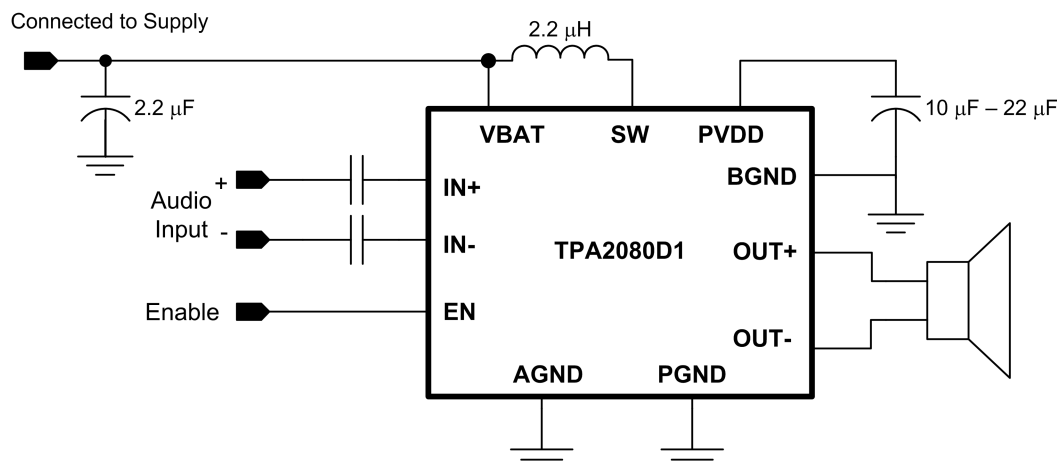
The TPA2080D1 is a high efficiency Class-D audio power amplifier with an integrated Class-G boost converter that enhances efficiency at low output power. It drives up to 2.2 W into an 4  $\Omega$  speaker (1% THD+N). With 85% typical efficiency, the TPA2080D1 helps extend battery life when playing audio.

The built-in boost converter generates a 5.75 V supply voltage for the Class-D amplifier when high output power is required. This provides a louder audio output than a stand-alone amplifier directly connected to the battery. During low audio output power periods, the boost converter deactivates and connects VBAT directly to the Class-D amplifier supply, PVDD. This improves overall efficiency.

The TPA2080D1 has an integrated low-pass filter to improve the RF rejection and reduce DAC out-of-band noise, increasing the signal-to-noise ratio (SNR).

The TPA2080D1 is available in a space saving 1.53 mm  $\times$  1.982 mm, 0.5 mm pitch WCSP package (YZG).

### SIMPLIFIED APPLICATION DIAGRAM

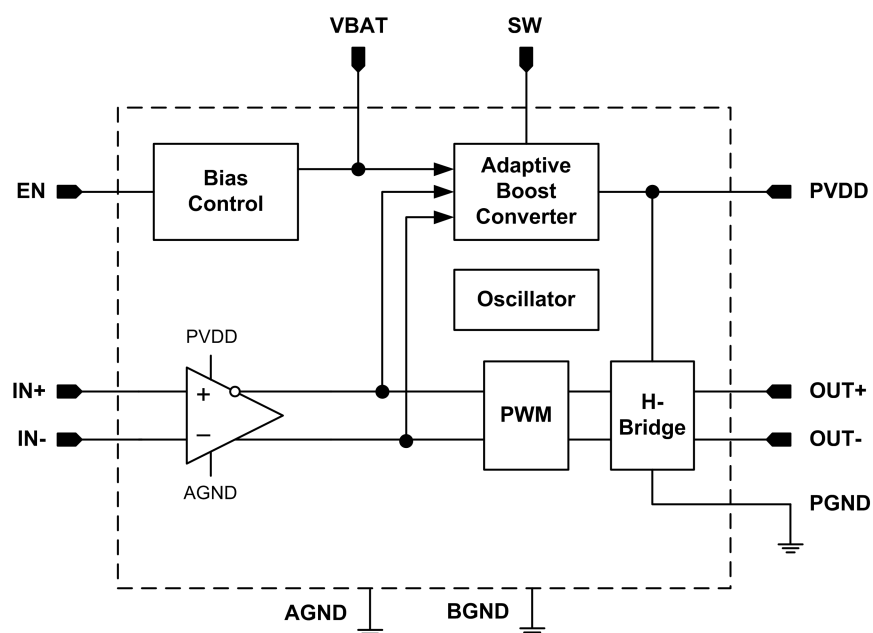


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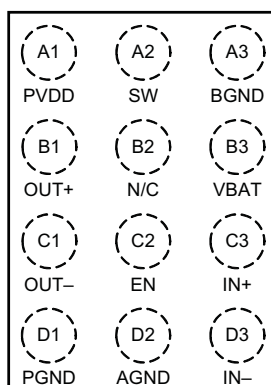
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## FUNCTIONAL BLOCK DIAGRAM



## DEVICE PINOUT

YZG Package  
(Top View)



## PIN FUNCTIONS

PIN		INPUT/ OUTPUT/ POWER (I/O/P)	DESCRIPTION
NAME	WCSP		
PVDD	A1	O	Boost converter output and Class-D power stage supply voltage.
SW	A2	I	Boost converter switch input; connect boost inductor between VBAT and SW.
BGND	A3	P	Boost converter power ground.
OUT+	B1	O	Positive audio output.
N/C	B2	–	No Connection
VBAT	B3	P	Supply voltage.
OUT–	C1	O	Negative audio output.
EN	C2	I	Device enable; set to logic high to enable.
IN+	C3	I	Positive audio input.
PGND	D1	P	Class-D power ground.
AGND	D2	P	Analog ground.
IN–	D3	I	Negative audio input.

## ORDERING INFORMATION

T <sub>A</sub>	PACKAGED DEVICES <sup>(1)</sup>	PART NUMBER <sup>(2)</sup>	SYMBOL
–40°C to 85°C	12-ball, 1.53 mm × 1.982 mm WSCP (DSBGA)	TPA2080D1YZGR	TPA2080D1
	12-ball, 1.53 mm × 1.982 mm WSCP (DSBGA)	TPA2080D1YZGT	TPA2080D1

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at [www.ti.com](http://www.ti.com).
- (2) The YZG package is only available taped and reeled. The suffix “R” indicates a reel of 3000, the suffix “T” indicates a reel of 250.

## ABSOLUTE MAXIMUM RATINGS

Over operating free–air temperature range, T<sub>A</sub> = 25°C (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Supply voltage	VBAT	–0.3	6	V
Input Voltage, V <sub>I</sub>	IN+, IN–	–0.3	VBAT + 0.3	V
Output continuous total power dissipation		See the Thermal Information Table		
Operating free-air temperature range, T <sub>A</sub>		–40	85	°C
Operating junction temperature range, T <sub>J</sub>		–40	150	°C
Storage temperature range, T <sub>STG</sub>		–65	150	°C
Minimum load resistance		3.2		Ω
ESD Protection	HBM		2000	V
	CDM		500	V
	MM		100	V

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.

## THERMAL INFORMATION

THERMAL METRIC <sup>(1)</sup>		TPA2080D1	UNITS
		YZG	
		12 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance	97.3	°C/W
$\theta_{JC(top)}$	Junction-to-case(top) thermal resistance	36.7	
$\theta_{JB}$	Junction-to-board thermal resistance	55.9	
$\psi_{JT}$	Junction-to-top characterization parameter	13.9	
$\psi_{JB}$	Junction-to-board characterization parameter	49.5	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
Supply voltage, VBAT	2.5	5.2	V
$V_{IH}$ High-level input voltage, END	1.3		V
$V_{IL}$ Low-level input voltage, END		0.6	V
$T_A$ Operating free-air temperature	–40	85	°C
$T_J$ Operating junction temperature	–40	150	°C

## ELECTRICAL CHARACTERISTICS

VBAT = 3.6 V,  $T_A = 25^\circ\text{C}$ ,  $R_L = 8\ \Omega + 33\ \mu\text{H}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VBAT supply voltage range		2.5		5.2	V
Class-D supply voltage range	EN = VBAT, boost converter active		5.75		V
	Boost converter disabled (in bypass mode)	2.5		5.2	
Supply under voltage shutdown			2.2		V
Operating quiescent current	EN = VBAT = 3.6 V		2.0	6	mA
Shutdown quiescent current	VBAT = 2.5 V to 5.2 V, EN = GND		0.2	1	$\mu\text{A}$
Input common-mode voltage range	IN+, IN–	0.6		1.3	V
Start-up time			6	10	ms

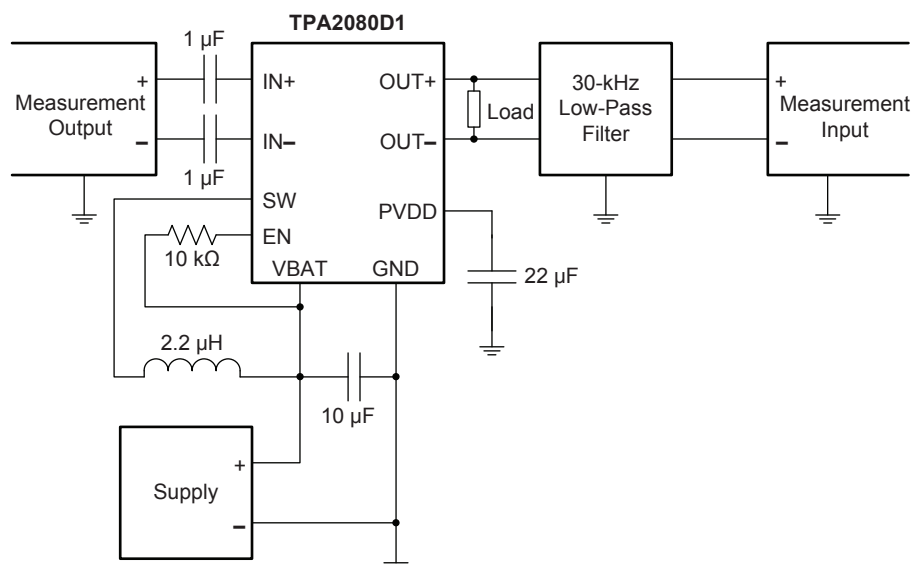
## OPERATING CHARACTERISTICS

VBAT = 3.6 V, EN = VBAT, T<sub>A</sub> = 25°C, R<sub>L</sub> = 8 Ω + 33 μH (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>BOOST CONVERTER</b>						
PVDD	Boost converter output voltage range	I <sub>BOOST</sub> = 0 mA	5.4	5.75	6.4	V
		I <sub>BOOST</sub> = 700 mA		5.6		V
I <sub>L</sub>	Boost converter input current limit	Power supply current		1800		mA
	Boost converter start-up current limit	Boost converter starts up from full shutdown		600		
		Boost converter wakes up from auto-pass through mode		1000		
f <sub>BOOST</sub>	Boost converter frequency			1.2		MHz
<b>CLASS-D AMPLIFIER</b>						
P <sub>O</sub>	Output power	THD = 1%, VBAT = 2.5 V, f = 1 kHz		1440		mW
		THD = 1%, VBAT = 3.0 V, f = 1 kHz		1750		
		THD = 1%, VBAT = 3.6 V, f = 1 kHz		1900		
		THD = 1%, VBAT = 2.5 V, f = 1 kHz, R <sub>L</sub> = 4 Ω + 33 μH		1460		
		THD = 1%, VBAT = 3.0 V, f = 1 kHz, R <sub>L</sub> = 4 Ω + 33 μH		1800		
		THD = 1%, VBAT = 3.6 V, f = 1 kHz, R <sub>L</sub> = 4 Ω + 33 μH		2280		
A <sub>V</sub>	Voltage gain		19.5	20	20.5	dB
V <sub>OOS</sub>	Output offset voltage			2	10	mV
	Short-circuit protection threshold current			2		A
R <sub>IN</sub>	Input impedance (per input pin)			24		kΩ
	Input impedance in shutdown (per input pin)	EN = 0 V		1300		
Z <sub>O</sub>	Output impedance in shutdown			2		kΩ
	Maximum input voltage swing	EN = 0 V		2		V <sub>RMS</sub>
	Boost converter auto-pass through threshold	Class-D output voltage threshold when boost converter automatically turns on		2		V <sub>PK</sub>
f <sub>CLASS-D</sub>	Class-D switching frequency		275	300	325	kHz
η	Class-D and boost combined efficiency	P <sub>O</sub> = 500 mW, VBAT = 3.6 V		90%		
E <sub>N</sub>	Noise output voltage	A-weighted		49		μV <sub>RMS</sub>
		Unweighted		65		
SNR	Signal-to-noise ratio	1.7 W, R <sub>L</sub> = 8 Ω + 33 μH. A-weighted		97.5		dB
		1.7 W, R <sub>L</sub> = 8 Ω + 33 μH. Unweighted		95		
		2 W, R <sub>L</sub> = 4 Ω + 33 μH. A-weighted		95		
		2 W, R <sub>L</sub> = 4 Ω + 33 μH. Unweighted		93		
THD+N	Total harmonic distortion plus noise <sup>(1)</sup>	P <sub>O</sub> = 100 mW, f = 1 kHz		0.06%		
		P <sub>O</sub> = 500 mW, f = 1 kHz		0.07%		
		P <sub>O</sub> = 1.7 W, f = 1 kHz, R <sub>L</sub> = 8 Ω + 33 μH		0.07%		
		P <sub>O</sub> = 2 W, f = 1 kHz, R <sub>L</sub> = 4 Ω + 33 μH		0.15%		
AC PSRR	AC-Power supply ripple rejection (output referred)	200 mV <sub>PP</sub> square ripple, V <sub>BAT</sub> = 3.8 V, f = 217 Hz		62.5		dB
		200 mV <sub>PP</sub> square ripple, V <sub>BAT</sub> = 3.8 V, f = 1 kHz		62.5		
AC CMRR	AC-Common mode rejection ratio (output referred)	200 mV <sub>PP</sub> square ripple, V <sub>BAT</sub> = 3.8 V, f = 217 Hz		71		dB
		200 mV <sub>PP</sub> square ripple, V <sub>BAT</sub> = 3.8 V, f = 1 kHz		71		

(1) A-weighted

## TEST SET-UP FOR GRAPHS



- (1) The 1  $\mu\text{F}$  input capacitors on IN+ and IN- were shorted for input common-mode voltage measurements.
- (2) A 33  $\mu\text{H}$  inductor was placed in series with the load resistor to emulate a small speaker for efficiency measurements.
- (3) The 30 kHz low-pass filter is required even if the analyzer has an internal low-pass filter. An R-C low-pass filter (100  $\Omega$ , 47 nF) is used on each output for the data sheet graphs.

## TYPICAL CHARACTERISTICS

$V_{BAT} = 3.6\text{ V}$ ,  $C_1 = 1\text{ }\mu\text{F}$ ,  $C_{BOOST} = 22\text{ }\mu\text{F}$ ,  $L_{BOOST} = 2.2\text{ }\mu\text{H}$ ,  $EN = V_{BAT}$ , and Load =  $8\text{ }\Omega + 33\text{ }\mu\text{H}$ , no ferrite bead unless otherwise specified.

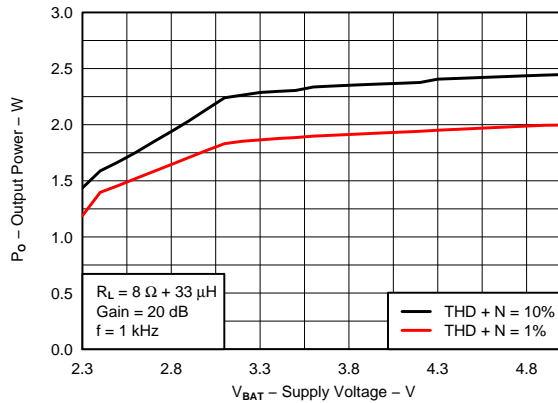


Figure 1. OUTPUT POWER vs SUPPLY VOLTAGE

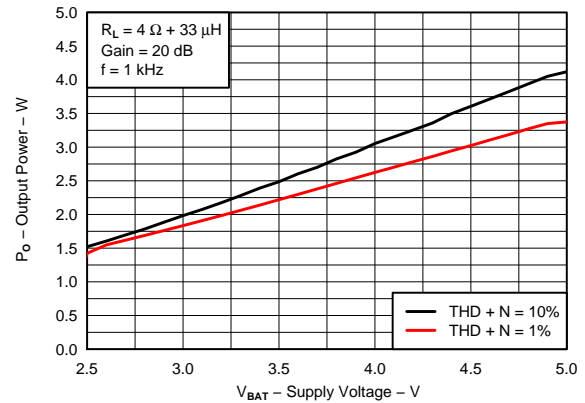


Figure 2. OUTPUT POWER vs SUPPLY VOLTAGE

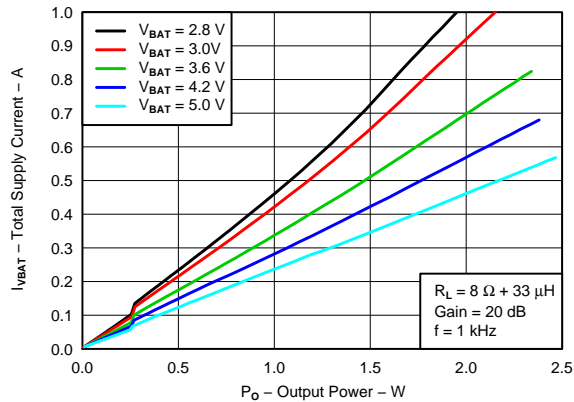


Figure 3. TOTAL SUPPLY CURRENT vs OUTPUT POWER

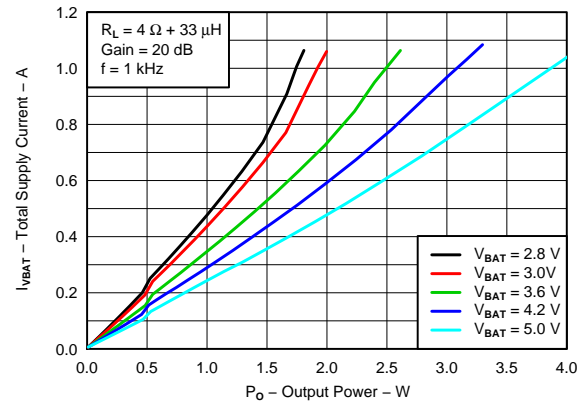


Figure 4. TOTAL SUPPLY CURRENT vs OUTPUT POWER

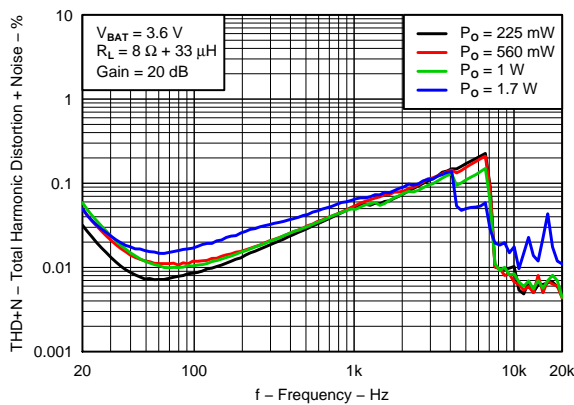


Figure 5. THD+N vs FREQUENCY

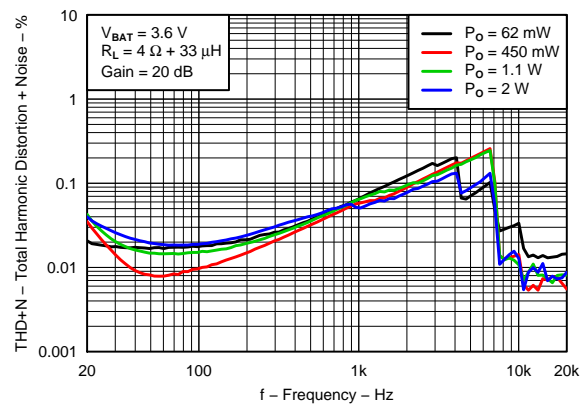


Figure 6. THD+N vs FREQUENCY

## TYPICAL CHARACTERISTICS (continued)

$V_{BAT} = 3.6\text{ V}$ ,  $C_I = 1\text{ }\mu\text{F}$ ,  $C_{BOOST} = 22\text{ }\mu\text{F}$ ,  $L_{BOOST} = 2.2\text{ }\mu\text{H}$ ,  $EN = V_{BAT}$ , and Load =  $8\text{ }\Omega + 33\text{ }\mu\text{H}$ , no ferrite bead unless otherwise specified.

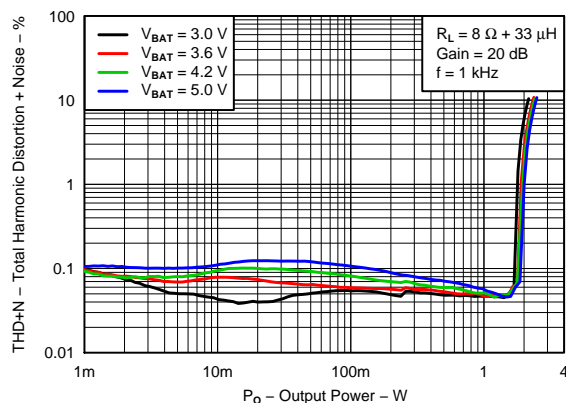


Figure 7. THD+N vs OUTPUT POWER

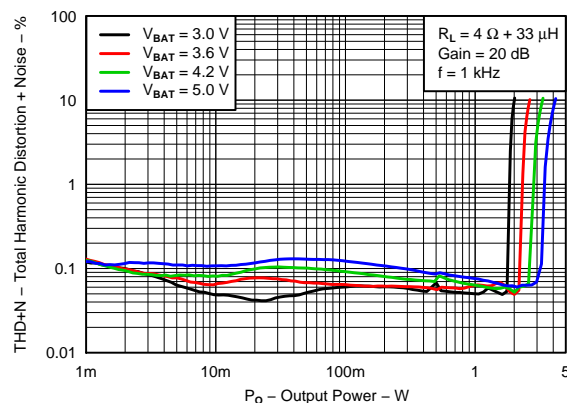


Figure 8. THD+N vs OUTPUT POWER

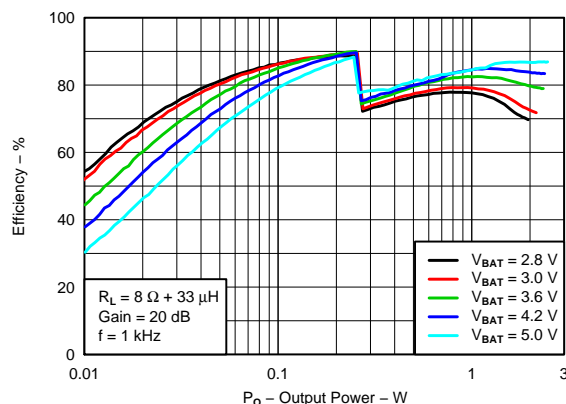


Figure 9. TOTAL EFFICIENCY vs OUTPUT POWER

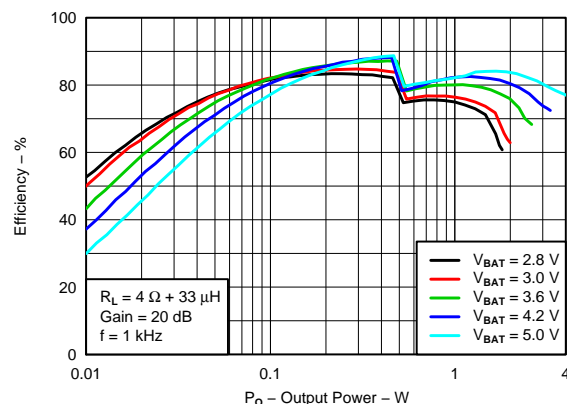


Figure 10. TOTAL EFFICIENCY vs OUTPUT POWER

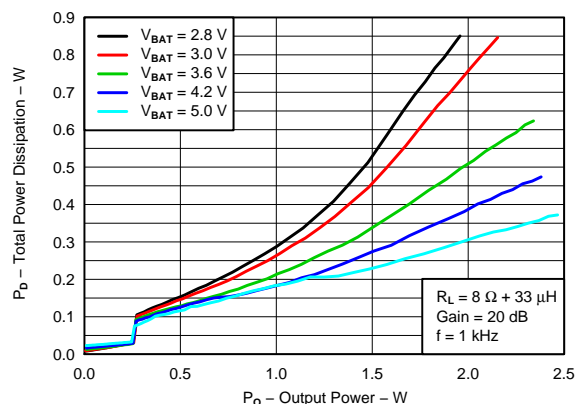


Figure 11. TOTAL POWER DISSIPATION vs OUTPUT POWER

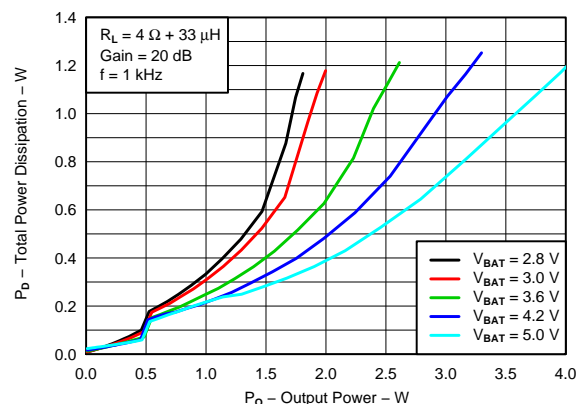


Figure 12. TOTAL POWER DISSIPATION vs OUTPUT POWER



## TYPICAL CHARACTERISTICS (continued)

$V_{BAT} = 3.6\text{ V}$ ,  $C_I = 1\text{ }\mu\text{F}$ ,  $C_{BOOST} = 22\text{ }\mu\text{F}$ ,  $L_{BOOST} = 2.2\text{ }\mu\text{H}$ ,  $EN = V_{BAT}$ , and Load =  $8\text{ }\Omega + 33\text{ }\mu\text{H}$ , no ferrite bead unless otherwise specified.

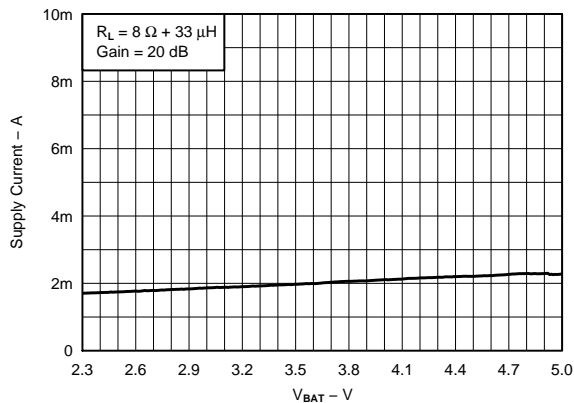


Figure 13. QUIESCENT SUPPLY CURRENT vs BATTERY VOLTAGE

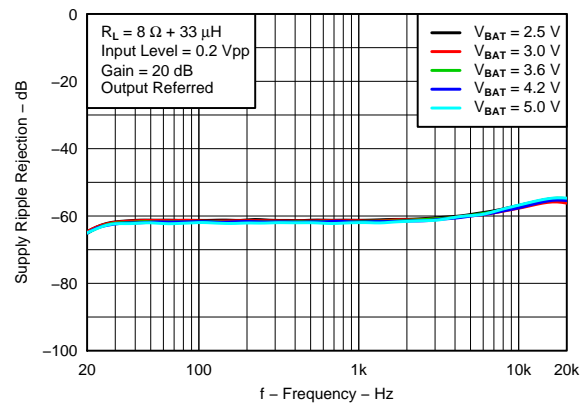


Figure 14. SUPPLY RIPPLE REJECTION vs FREQUENCY

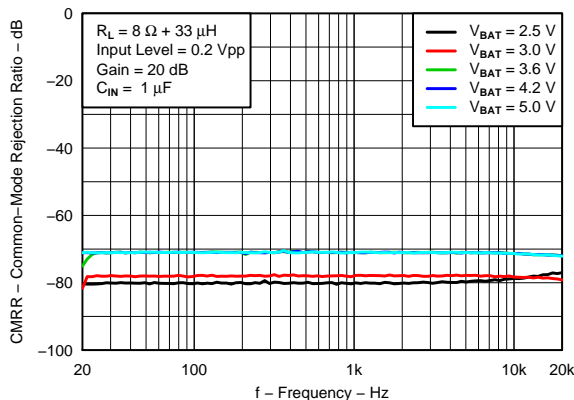


Figure 15. COMMON-MODE REJECTION RATIO vs FREQUENCY

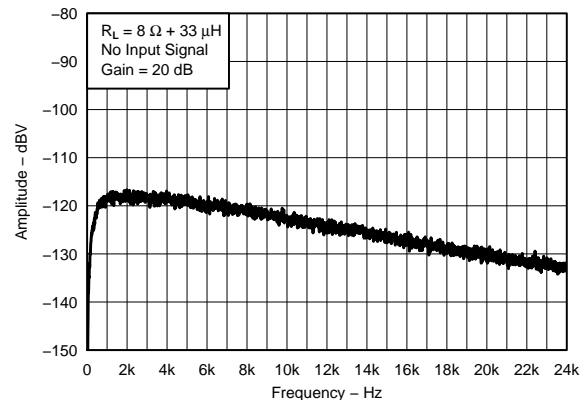


Figure 16. A-WEIGHTED OUTPUT NOISE vs FREQUENCY

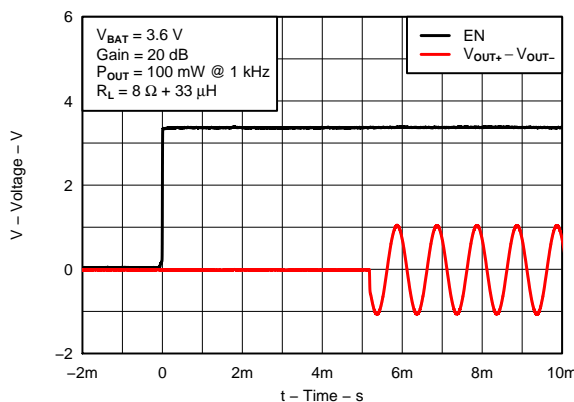


Figure 17. STARTUP TIMING

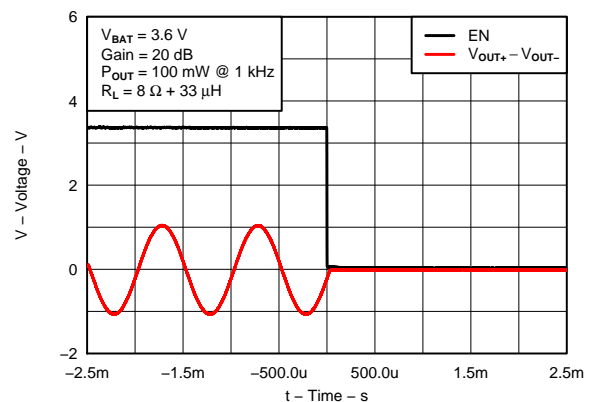


Figure 18. SHUTDOWN TIMING

### TYPICAL CHARACTERISTICS (continued)

V<sub>BAT</sub> = 3.6 V, C<sub>I</sub> = 1  $\mu$ F, C<sub>BOOST</sub> = 22  $\mu$ F, L<sub>BOOST</sub> = 2.2  $\mu$ H, EN = V<sub>BAT</sub>, and Load = 8  $\Omega$  + 33  $\mu$ H, no ferrite bead unless otherwise specified.

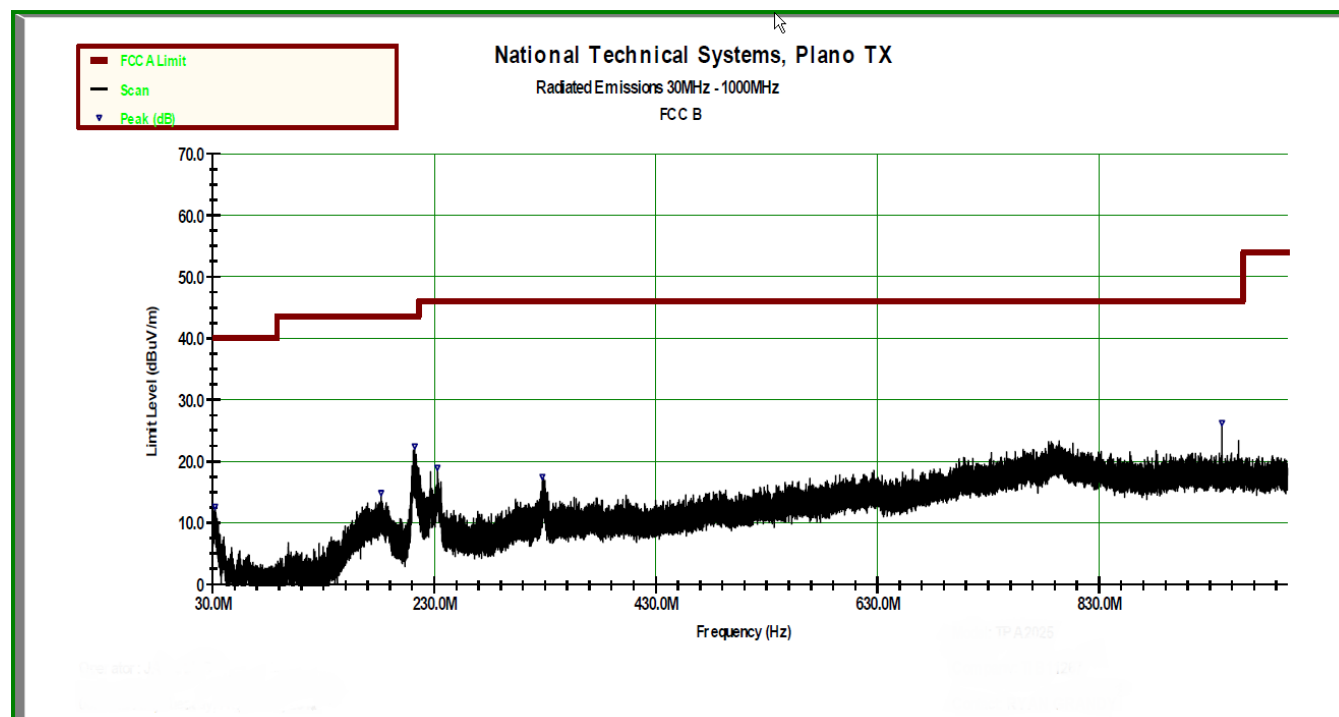


Figure 19. EMC PERFORMANCE P<sub>O</sub> = 750 mW with 2 INCH SPEAKER CABLE

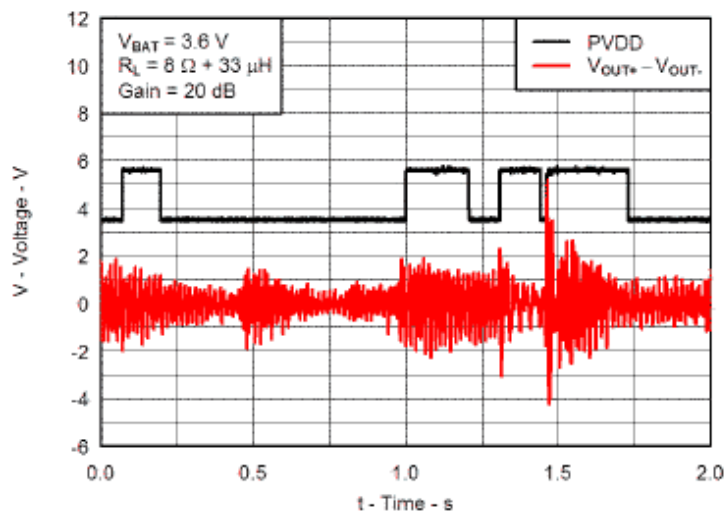
## BOOST CONVERTER AUTO PASS THROUGH (APT)

The TPA2080D1 consists of a Class-G boost converter and a Class-D amplifier. The boost converter operates from the supply voltage, VBAT, and generates a higher output voltage PVDD at 5.75 V. PVDD drives the supply voltage of the Class-D amplifier. This improves loudness over non-boosted solutions. The boost converter has a “Pass Through” mode in which it turns off automatically and PVDD is directly connected to VBAT through an internal bypass switch.

The boost converter is adaptive and operates between pass through mode and boost mode depending on the output audio signal amplitude. When the audio output amplitude exceeds the “auto pass through” (APT) threshold, the boost converter is activated automatically and goes to boost mode. The transition time from normal mode to boost mode is fast enough to prevent clipping large transient audio signals. TPA2080D1’s APT threshold is fixed at  $2 V_{PEAK}$ . When the audio output signal is below APT threshold, the boost converter is deactivated and goes to pass through mode. The adaptive boost converter maximizes system efficiency at lower audio output levels.

The Class-G boost converter is designed to drive the Class-D amplifier only. Do not use the boost converter to drive external devices.

Figure 20 shows how the adaptive boost converter behaves with a typical audio signal.



**Figure 20. Class-G Boost Converter with Typical Music Playback**

## BOOST CONVERTER COMPONENT SECTION

The critical external components are summarized in the following table:

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Boost converter inductor	At 30% rated DC bias current of the inductor	1.5	2.2	4.7	μH
Boost converter input capacitor		4.7		10	μF
Boost converter output capacitor	Working capacitance biased at boost output voltage, if 4.7μH inductor is chosen, then minimum capacitance is 10 μF	4.7		22	μF

### Boost Terms

The following is a list of terms and definitions used in the boost equations found later in this document.

C	Minimum boost capacitance required for a given ripple voltage on PVDD.
L	Boost inductor
$f_{\text{BOOST}}$	Switching frequency of the boost converter.
$I_{\text{PVDD}}$	Current pulled by the Class-D amplifier from the boost converter.
$I_L$	Average current through the boost inductor.
PVDD	Supply voltage for the Class-D amplifier. (Voltage generated by the boost converter output)
VBAT	Supply voltage to the IC.
$\Delta I_L$	Ripple current through the inductor.
$\Delta V$	Ripple voltage on PVDD.

### Inductor Equations

Inductor current rating is determined by the requirements of the load. The inductance is determined by two factors: the minimum value required for stability and the maximum ripple current permitted in the application. Use [Equation 1](#) to determine the required current rating. [Equation 1](#) shows the approximate relationship between the average inductor current,  $I_L$ , to the load current, load voltage, and input voltage ( $I_{\text{PVDD}}$ , PVDD, and VBAT, respectively). Insert  $I_{\text{PVDD}}$ , PVDD, and VBAT into Equation 1 and solve for  $I_L$ . The inductor must maintain at least 90% of its initial inductance value at this current.

$$I_L = I_{\text{PVDD}} \times \left( \frac{\text{PVDD}}{\text{VBAT} \times 0.8} \right) \quad (1)$$

Ripple current,  $\Delta I_L$ , is peak-to-peak variation in inductor current. Smaller ripple current reduces core losses in the inductor and reduces the potential for EMI. Use [Equation 2](#) to determine the value of the inductor, L. [Equation 2](#) shows the relationship between inductance L, VBAT, PVDD, the switching frequency,  $f_{\text{BOOST}}$ , and  $\Delta I_L$ . Insert the maximum acceptable ripple current into [Equation 2](#) and solve for L.

$$L = \frac{\text{VBAT} \times (\text{PVDD} - \text{VBAT})}{\Delta I_L \times f_{\text{BOOST}} \times \text{PVDD}} \quad (2)$$

$\Delta I_L$  is inversely proportional to L. Minimize  $\Delta I_L$  as much as is necessary for a specific application. Increase the inductance to reduce the ripple current. Do not use greater than 4.7 μH, as this prevents the boost converter from responding to fast output current changes properly. If using above 3.3 μH, then use at least 10 μF capacitance on PVDD to ensure boost converter stability.

The typical inductor value range for the TPA2080D1 is 2.2 μH to 3.3 μH. Select an inductor with less than 0.5 Ω dc resistance, DCR. Higher DCR reduces total efficiency due to an increase in voltage drop across the inductor.

**Table 1. Sample Inductors**

L (μH)	SUPPLIER	COMPONENT CODE	SIZE (LxWxH mm)	DCR TYP (mΩ)	I <sub>SAT</sub> MAX (A)	C RANGE
2.2	Chilisin Electronics Corp.	CLCN252012T-2R2M-N	2.5 x 2.0 x 1.2	105	1.2	10 - 22 μF / 16 V 10 - 22 μF / 10 V
2.2	Toko	1239AS-H-2R2N=P2	2.5 x 2.0 x 1.2	96	2.3	
2.2	Coilcraft	XFL4020-222MEC	4.0 x 4.0 x 2.15	22	3.5	
3.3	Toko	1239AS-H-3R3N=P2	2.5 x 2.0 x 1.2	160	2.0	10 - 22 μF / 10 V
3.3	Coilcraft	XFL4020-332MEC	4.0 x 4.0 x 2.15	35	2.8	

## Boost Converter Capacitor Selection

The value of the boost capacitor is determined by the minimum value of working capacitance required for stability and the maximum voltage ripple allowed on PVDD in the application. Working capacitance refers to the available capacitance after derating the capacitor value for DC bias, temperature, and aging. Do not use any component with a working capacitance less than 6.8 μF. This corresponds to a 10 μF/16 V capacitor or a 10 μF/10 V capacitor.

Do not use above 22 μF capacitance as it will reduce the boost converter response time to large output current transients.

[Equation 3](#) shows the relationship between the boost capacitance, C, to load current, load voltage, ripple voltage, input voltage, and switching frequency (I<sub>PVDD</sub>, PVDD, ΔV, VBAT, and f<sub>BOOST</sub> respectively).

Insert the maximum allowed ripple voltage into [Equation 3](#) and solve for C. The 1.5 multiplier accounts for capacitance loss due to applied dc voltage and temperature for X5R and X7R ceramic capacitors.

$$C = 1.5 \times \frac{I_{PVDD} \times (PVDD - VBAT)}{\Delta V \times f_{BOOST} \times PVDD} \quad (3)$$

## COMPONENTS LOCATION AND SELECTION

### Decoupling Capacitors

The TPA2080D1 is a high-performance Class-D audio amplifier that requires adequate power supply decoupling. Adequate power supply decoupling to ensures that the efficiency is high and total harmonic distortion (THD) is low.

Place a low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1 μF, within 2 mm of the VBAT ball. Use X5R and X7R ceramic capacitors. This choice of capacitor and placement helps with higher frequency transients, spikes, or digital hash on the line. Additionally, placing this decoupling capacitor close to the TPA2080D1 is important, as any parasitic resistance or inductance between the device and the capacitor causes efficiency loss. In addition to the 0.1 μF ceramic capacitor, place a 2.2 μF to 10 μF capacitor on the VBAT supply trace. This larger capacitor acts as a charge reservoir, providing energy faster than the board supply, thus helping to prevent any droop in the supply voltage.

### Input Capacitors

Input audio DC decoupling capacitors are recommended. The input capacitors and TPA2080D1 input impedance form a high-pass filter with the corner frequency, f<sub>c</sub>, determined in [Equation 4](#).

Any mismatch in capacitance between the two inputs will cause a mismatch in the corner frequencies. Severe mismatch may also cause turn-on pop noise. Choose capacitors with a tolerance of ±10% or better. Use X5R and X7R ceramic capacitors.

$$f_c = \frac{1}{(2 \times \pi \times R_i C_i)} \quad (4)$$

## SHORT CIRCUIT AUTO-RECOVERY

When a short circuit event happens, the TPA2080D1 goes to low duty cycle mode and tries to reactivate itself every 1.6 seconds. The auto-recovery will continue until the short circuit event stops. This feature protects the device without affecting the device's long term reliability.

## THERMAL PROTECTION

It is important to operate the TPA2080D1 at temperatures lower than its maximum operating temperature. The maximum ambient temperature depends on the heat-sinking ability of the PCB system. Given  $\theta_{JA}$  of 97.3°C/W, the maximum allowable junction temperature of 150°C, and the internal dissipation of 0.5 W for 1.9 W, 8  $\Omega$  load, 3.6 V supply, the maximum ambient temperature is calculated as:

$$T_{A,MAX} = T_{J,MAX} - \theta_{JA}P_D = 150^{\circ}\text{C} - (97.3^{\circ}\text{C/W} \times 0.5 \text{ W}) = 101.4^{\circ}\text{C}$$

The calculated maximum ambient temperature is 101.4°C at maximum power dissipation at 3.6 V supply and 8  $\Omega$  load. The TPA2080D1 is designed with thermal protection that turns the device off when the junction temperature surpasses 150°C to prevent damage to the IC.

## OPERATION WITH DACS AND CODECS

Large noise voltages can be present at the output of  $\Delta\Sigma$  DACs and CODECs, just above the audio frequency (e.g: 80 kHz with a 300 mV<sub>P-P</sub>). This out-of-band noise is due to the noise shaping of the delta-sigma modulator in the DAC. Some Class-D amplifiers have higher output noise when used in combination with these DACs and CODECs. This is because out-of-band noise from the CODEC/DAC mixes with the Class-D switching frequencies in the audio amplifier input stage. The TPA2080D1 has a built-in low-pass filter with cutoff frequency at 55 kHz that reduces the out-of-band noise and RF noise, filtering out-of-band frequencies that could degrade in-band noise performance. If driving the TPA2080D1 input with 4th-order or higher  $\Delta\Sigma$  DACs or CODECs, add an R-C low pass filter at each of the audio inputs (IN+ and IN-) of the TPA2080D1 to ensure best performance. The recommended resistor value is 100  $\Omega$  and the capacitor value of 47 nF.

## SPEAKER LOAD LIMITATION

Speakers are non-linear loads with varying impedance (magnitude and phase) over the audio frequency. A portion of speaker load current can flow back into the boost converter output via the Class-D output H-bridge high-side device. This is dependent on the speaker's phase change over frequency, and the audio signal amplitude and frequency content. Most portable speakers have limited phase change at the resonant frequency, typically no more than 40 or 50 degrees. To avoid excess flow-back current, use speakers with limited phase change. Otherwise, flow-back current could drive the PVDD voltage above the absolute maximum recommended operational voltage.

Confirm proper operation by connecting the speaker to the TPA2080D1 and driving it at maximum output swing. Observe the PVDD voltage with an oscilloscope. In the unlikely event the PVDD voltage exceeds 6.5 V, add a 6.8 V Zener diode between PVDD and ground to ensure the TPA2080D1 operates properly. The amplifier has thermal overload protection and deactivates if the die temperature exceeds 150°C. It automatically reactivates once die temperature returns below 150°C. Built-in output over-current protection deactivates the amplifier if the speaker load becomes short-circuited. The amplifier automatically restarts 1.6 seconds after the over-current event. Although the TPA2080D1 Class-D output can withstand a short between OUT+ and OUT-, do not connect either output directly to GND, VDD, or VBAT as this could damage the device.

## PACKAGE DIMENSIONS

The TPA2080D1 uses a 12-ball, 0.5 mm pitch WCSP package. The die length (D) and width (E) correspond to the package mechanical drawing at the end of the datasheet.

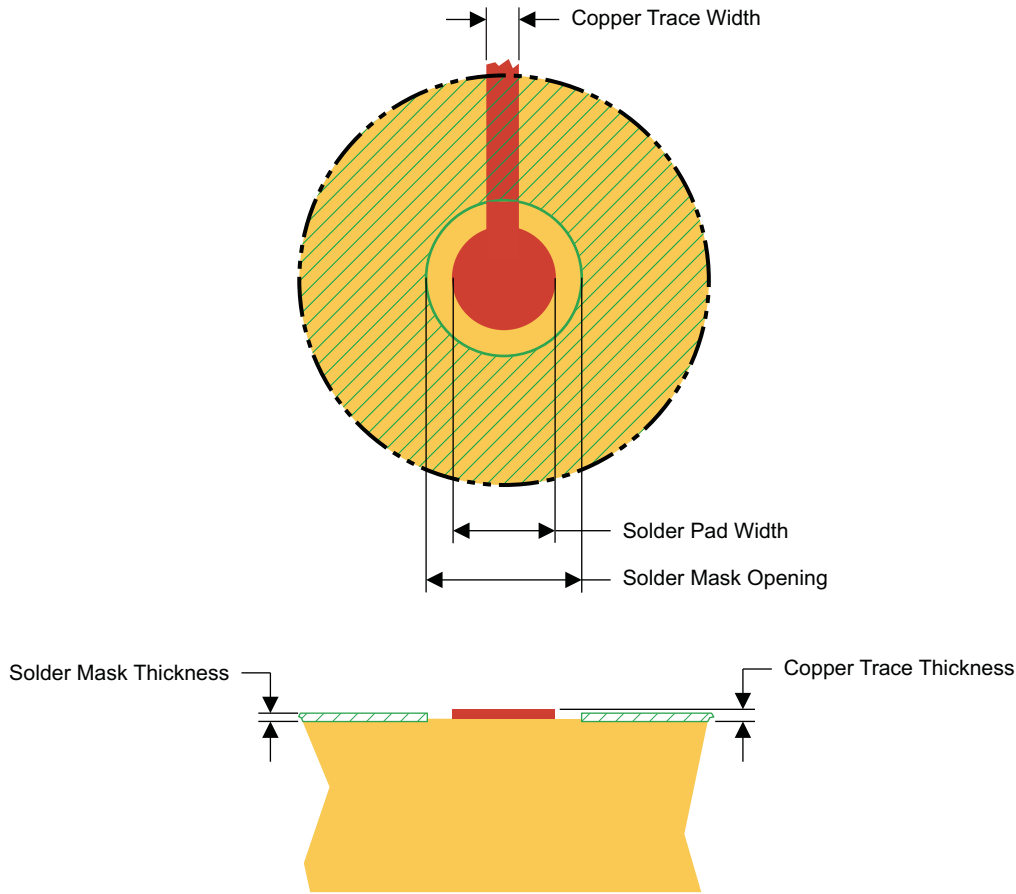
**Table 2. TPA2080D1 YZG Package Dimensions**

Dimension	D	E
Max	2012 $\mu\text{m}$	1560 $\mu\text{m}$
Typ	1982 $\mu\text{m}$	1530 $\mu\text{m}$
Min	1952 $\mu\text{m}$	1500 $\mu\text{m}$

## BOARD LAYOUT

TPA2080D1 has AGND, BGND and PGND for analog circuit, boost converter and Class-D amplifier respectively. These three ground pins should be connected together through a solid ground plane with multiple ground VIAs.

In making the pad size for the WCSP balls, it is recommended that the layout use non-solder mask defined (NSMD) land. With this method, the solder mask opening is made larger than the desired land area, and the opening size is defined by the copper pad width. Figure 21 shows the appropriate diameters for a WCSP layout.



M0200-01

**Figure 21. Land Pattern Dimensions**

**Table 3. Land Pattern Dimensions<sup>(1) (2) (3) (4)</sup>**

SOLDER PAD DEFINITIONS	COPPER PAD	SOLDER MASK OPENING <sup>(5)</sup>	COPPER THICKNESS	STENCIL OPENING <sup>(6) (7)</sup>	STENCIL THICKNESS
Nonsolder mask defined (NSMD)	275 $\mu\text{m}$ (+0.0, -25 $\mu\text{m}$ )	375 $\mu\text{m}$ (+0.0, -25 $\mu\text{m}$ )	1 oz max (32 $\mu\text{m}$ )	275 $\mu\text{m}$ x 275 $\mu\text{m}$ Sq. (rounded corners)	125 $\mu\text{m}$ thick

- (1) Circuit traces from NSMD defined PWB lands should be 75  $\mu\text{m}$  to 100  $\mu\text{m}$  wide in the exposed area inside the solder mask opening. Wider trace widths reduce device stand off and impact reliability.
- (2) Best reliability results are achieved when the PWB laminate glass transition temperature is above the operating the range of the intended application.
- (3) Recommend solder paste is Type 3 or Type 4.
- (4) For a PWB using a Ni/Au surface finish, the gold thickness should be less 0.5  $\mu\text{m}$  to avoid a reduction in thermal fatigue performance.
- (5) Solder mask thickness should be less than 20  $\mu\text{m}$  on top of the copper circuit pattern
- (6) Best solder stencil performance is achieved using laser cut stencils with electro polishing. Use of chemically etched stencils results in inferior solder paste volume control.
- (7) Trace routing away from WCSP device should be balanced in X and Y directions to avoid unintentional component movement due to solder wetting forces.

## REVISION HISTORY

Changes from Original (January 2012) to Revision A	Page
• Changed Feature From: Available in 1.53 mm × 1.98 mm, 0.5 mm pitch 12-ball WCSP Package To: Available in 1.53 mm × 1.98 mm, 0.5 mm pitch 12-ball WCSP (DSBGA) Package .....	1
• Added (DSBGA) to the Packaged Devices of the ORDERING INFORMATION table .....	3



## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPA2080D1YZGR	ACTIVE	DSBGA	YZG	12	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	TPA2080D1	<a href="#">Samples</a>
TPA2080D1YZGT	ACTIVE	DSBGA	YZG	12	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	TPA2080D1	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

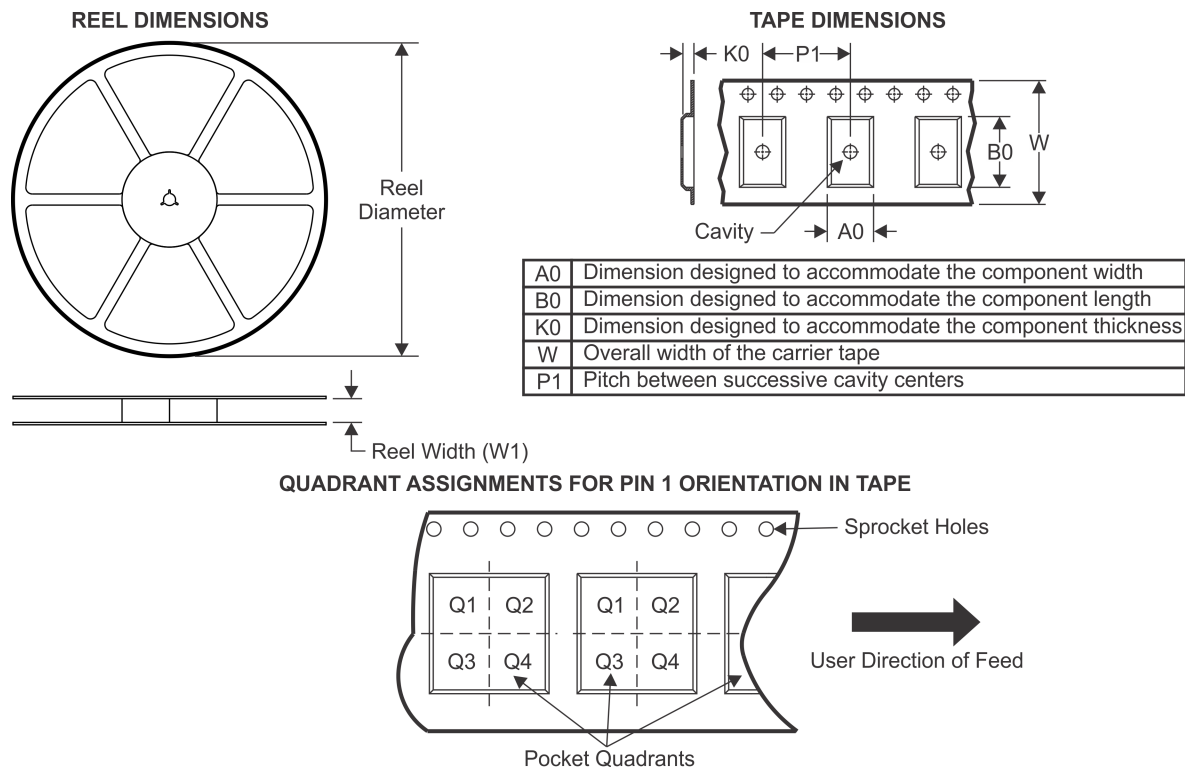
**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA2080D1YZGR	DSBGA	YZG	12	3000	180.0	8.4	1.63	2.08	0.69	4.0	8.0	Q1
TPA2080D1YZGT	DSBGA	YZG	12	250	180.0	8.4	1.63	2.08	0.69	4.0	8.0	Q1

## TAPE AND REEL BOX DIMENSIONS

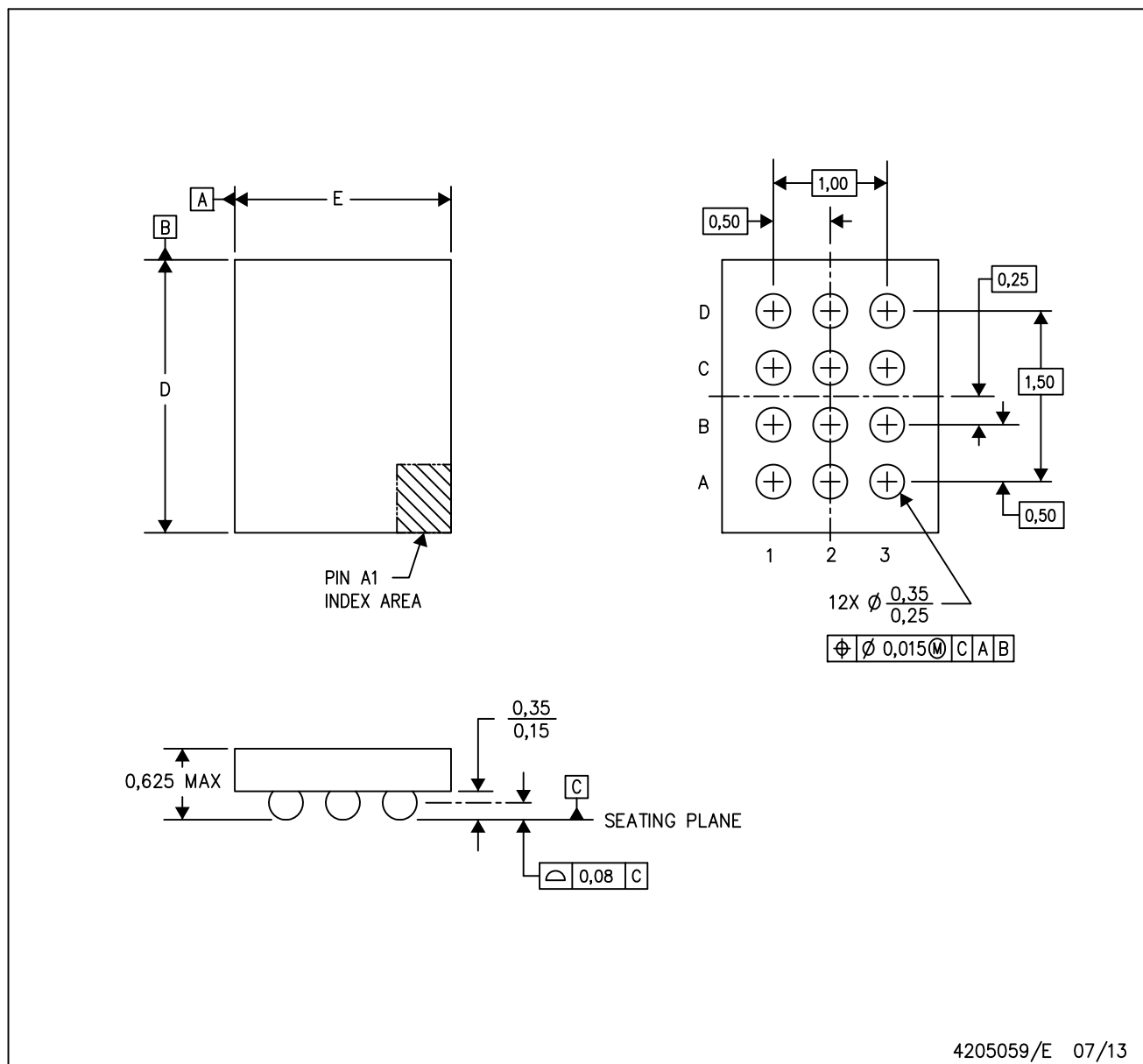


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA2080D1YZGR	DSBGA	YZG	12	3000	182.0	182.0	17.0
TPA2080D1YZGT	DSBGA	YZG	12	250	182.0	182.0	17.0

YZG (R-XBGA-N12)

DIE-SIZE BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.  
 B. This drawing is subject to change without notice.  
 C. NanoFree™ package configuration.

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